

Peak pulse voltage (Tj=25 ; non-repetitive, off-state; FIG.8)	Vpp	2.5	kV
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ELECTRICAL CHARACTERISTICS (unless otherwise specified)

Symbol Test Condition Quadrant

FIG.7: Relative variations of gate trigger current, holding current and latching current versus junction temperature

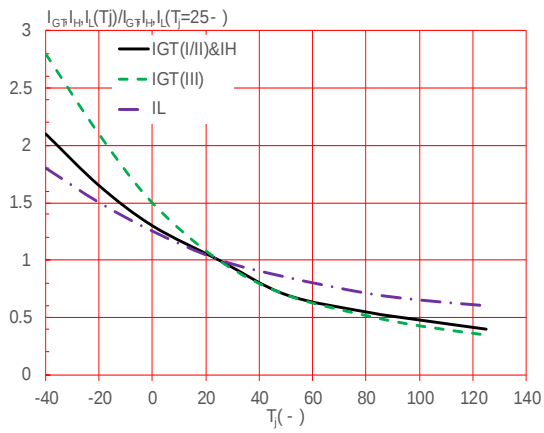
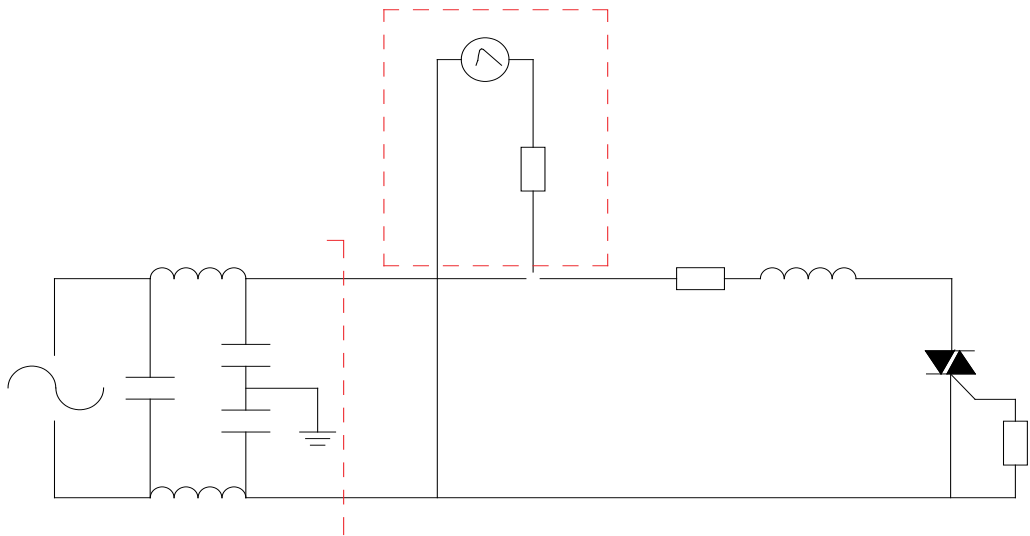


FIG.8: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



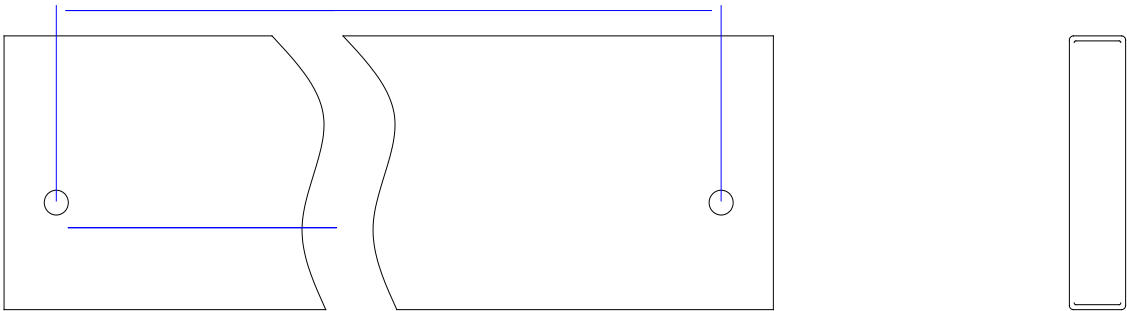
ORDERING INFORMATION

Order cœle	Vœt age V _{DRM} /V _{RRM} (V)	IGT(mA)	Package	Base q y. (œs)	Deli very œœle
		H- I- J			
JST24E-1200CW	1200	35	TO-263	50	Tube
JST24E-1200CW-TR					

Document Revi si œn Hi st œy

Revision

DELIVERY MODE



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